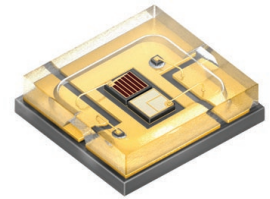


# LE BR Q7WM

## OSRAM OSTAR® Projection Compact

Compact light source in SMT technology, glass window on top, RoHS compliant



### Applications

- Augmented Reality, Mixed Reality
- Gaming (AR/VR)
- Projection Mobile (LED & Laser)
- Virtual Reality

### Features:

- Package: compact lightsource in SMT technology with glass window on top
- Chip technology: Thinfilm / ThinGaN
- Typ. Radiation: 120° (Lambertian emitter)
- Color:  $\lambda_{\text{dom}} = 460 \text{ nm}$  (● blue);  $\lambda_{\text{dom}} = 617 \text{ nm}$  (● red)
- Corrosion Robustness Class: 3B
- ESD: 2 kV acc. to ANSI/ESDA/JEDEC JS-001 (HBM)

### Ordering Information

Type	Brightness <sup>1)</sup>	Ordering Code
LE BR Q7WM-TGTI-24+JXJZ-23		Q65112A7832
● blue	● $\Phi_{\text{E}} = 280 \dots 450 \text{ mW}$ ( $I_{\text{F}} = 350 \text{ mA}$ )	
● red	● $\Phi_{\text{V}} = 45 \dots 71 \text{ lm}$ ( $I_{\text{F}} = 350 \text{ mA}$ )	

## Maximum Ratings

Parameter	Symbol		Values	
			• blue	• red
Operating Temperature	$T_{op}$	min.	-40 °C	-40 °C
		max.	85 °C	85 °C
Storage Temperature	$T_{stg}$	min.	-40 °C	-40 °C
		max.	85 °C	85 °C
Junction Temperature	$T_j$	max.	125 °C	125 °C
Forward Current $T_j = T_{jmax.}$	$I_F$	min.	20 mA	20 mA
		max.	500 mA	500 mA
Forward Current pulsed $f = 240\text{Hz}; D = 0.5; T_j = T_{jmax.}$	$I_{F pulse}$		1000 mA	1000 mA
Surge Current $t \leq 10\mu\text{s}; D = 0.5; T_j = T_{jmax.}$	$I_{FS}$	max.	1500 mA	1500 mA
ESD withstand voltage acc. to ANSI/ESDA/JEDEC JS-001 (HBM)	$V_{ESD}$		2 kV	2 kV
Reverse current <sup>2)</sup>	$I_R$	max.	200 mA	200 mA

## Characteristics

$I_F = 350 \text{ mA}$ ;  $T_S = 25 \text{ °C}$

Parameter	Symbol		Values	
			● blue	● red
Peak Wavelength	$\lambda_{\text{peak}}$	typ.	460 nm	624 nm
Dominant Wavelength <sup>3)</sup>	$\lambda_{\text{dom}}$	min.	450 nm	610 nm
		typ.	460 nm	617 nm
		max.	465 nm	622 nm
Spectral bandwidth at 50% $I_{\text{rel,max}}$	$\Delta\lambda$	typ.	19 nm	18 nm
Viewing angle at 50% $I_V$	$2\varphi$	typ.	120 °	120 °
Radiating surface	$A_{\text{color}}$	typ.	0.65 x 0.65 mm <sup>2</sup>	0.65 x 0.65 mm <sup>2</sup>
Partial Flux acc. CIE 127:2007 <sup>4)</sup> $\Phi_{E/V 120^\circ} = x * \Phi_{E/V 180^\circ}$	$\Phi_{E/V, 120^\circ}$	typ.	0.82	0.82
Forward Voltage <sup>5)</sup> $I_F = 350 \text{ mA}$	$V_F$	min.	2.70 V	2.00 V
		typ.	3.40 V	2.30 V
		max.	3.70 V	2.70 V
Reverse voltage (ESD device)	$V_{\text{RESD}}$	min.	45 V	45 V
Reverse voltage <sup>2)</sup> $I_R = 20 \text{ mA}$	$V_R$	max.	1.2 V	1.2 V
Real thermal resistance junction/solderpoint <sup>6)</sup> 1 Chip on	$R_{\text{thJS real}}$	typ.	16 K / W	14 K / W
		max.	19 K / W	17 K / W
Electrical thermal resistance junction/solderpoint <sup>6)</sup> 1 Chip on with efficiency $\eta_e = 29 \text{ %}$ (blue); $27 \text{ %}$ (red)	$R_{\text{thJS elec.}}$	typ.	11 K / W	10 K / W
		max.	13 K / W	12 K / W

## Brightness Groups

- blue

Group	Radiant Flux <sup>1)</sup> $I_F = 350 \text{ mA}$ min. $\Phi_E$	Radiant Flux <sup>1)</sup> $I_F = 350 \text{ mA}$ max. $\Phi_E$
TG	280 mW	330 mW
TH	330 mW	390 mW
TI	390 mW	450 mW

## Brightness Groups

- red

Group	Luminous Flux <sup>3)</sup> $I_F = 350 \text{ mA}$ min. $\Phi_V$	Luminous Flux <sup>1)</sup> $I_F = 350 \text{ mA}$ max. $\Phi_V$
JX	45 lm	52 lm
JY	52 lm	61 lm
JZ	61 lm	71 lm

## Wavelength Groups

- blue

Group	Dominant Wavelength <sup>3)</sup> min. $\lambda_{\text{dom}}$	Dominant Wavelength <sup>3)</sup> max. $\lambda_{\text{dom}}$
2	450 nm	455 nm
3	455 nm	460 nm
4	460 nm	465 nm

## Wavelength Groups

- red

Group	Dominant Wavelength <sup>3)</sup> min. $\lambda_{\text{dom}}$	Dominant Wavelength <sup>3)</sup> max. $\lambda_{\text{dom}}$
2	610 nm	616 nm
3	616 nm	622 nm

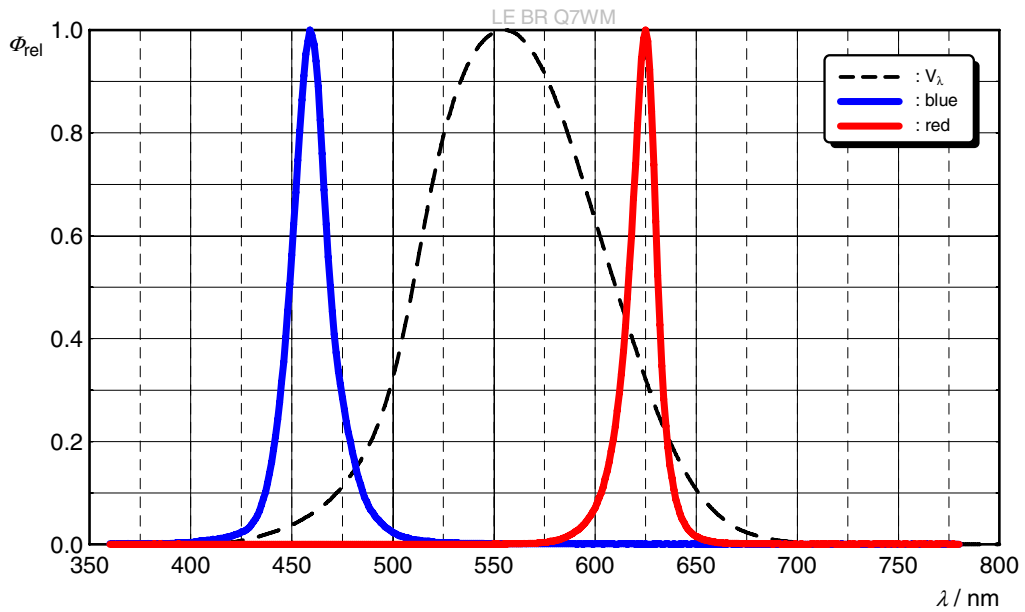
## Group Name on Label

Example: TG-2+JX-2

Color	Brightness	Wavelength
• blue	TG	2
• red	JX	2

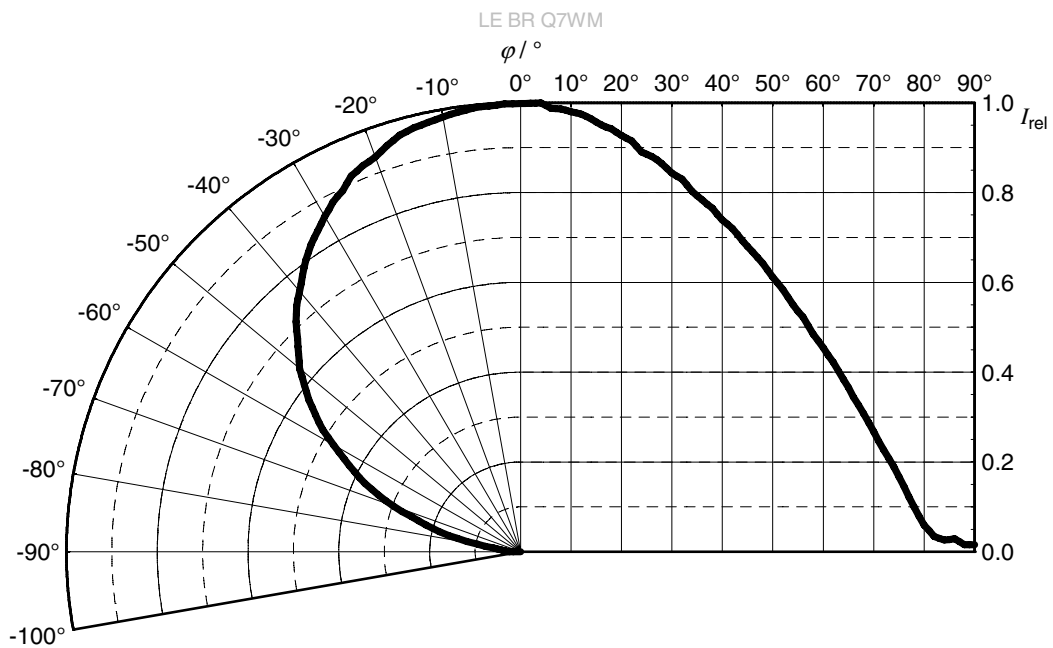
### Relative Spectral Emission <sup>4)</sup>

$\Phi_{rel} = f(\lambda)$ ;  $I_F = 350 \text{ mA}$ ;  $T_J = 25 \text{ }^\circ\text{C}$



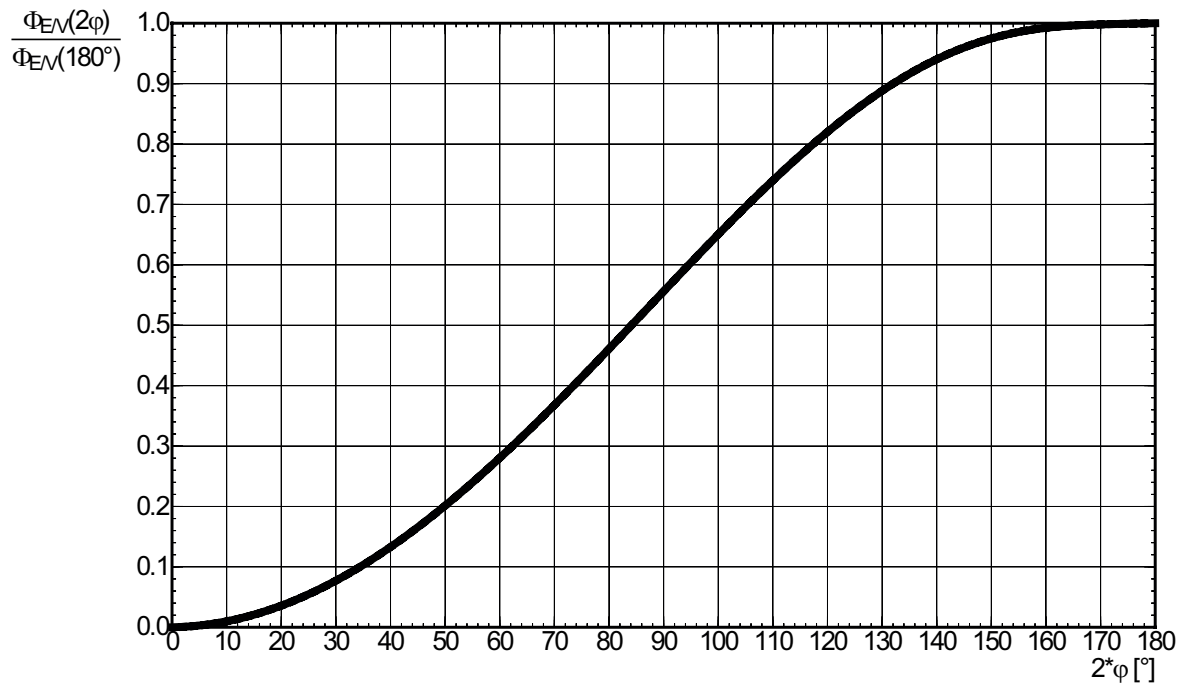
### Radiation Characteristics <sup>4)</sup>

$I_{rel} = f(\phi)$ ;  $T_J = 25 \text{ }^\circ\text{C}$



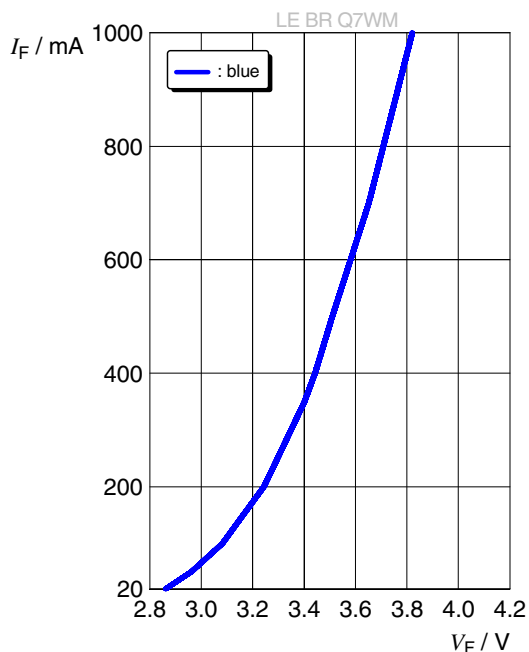
**Relative Partial Flux** <sup>4)</sup>

$$\Phi_{\text{V/E}}(2\varphi)/\Phi_{\text{V/E}}(180^\circ) = f(\varphi); T_j = 25^\circ\text{C}$$



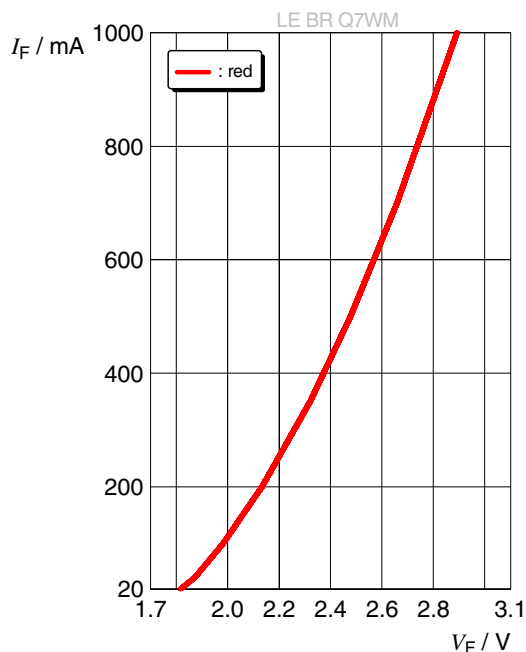
**Forward current** 4), 7)

$I_F = f(V_F); T_J = 25\text{ }^\circ\text{C}$



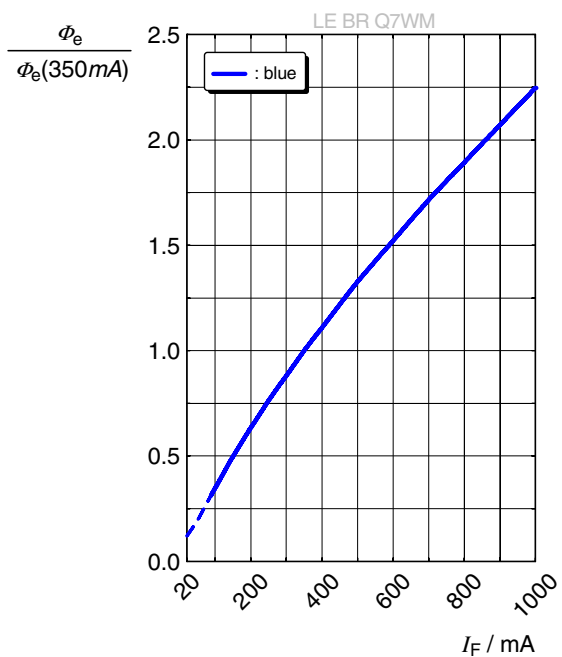
**Forward current** 4), 7)

$I_F = f(V_F); T_J = 25\text{ }^\circ\text{C}$



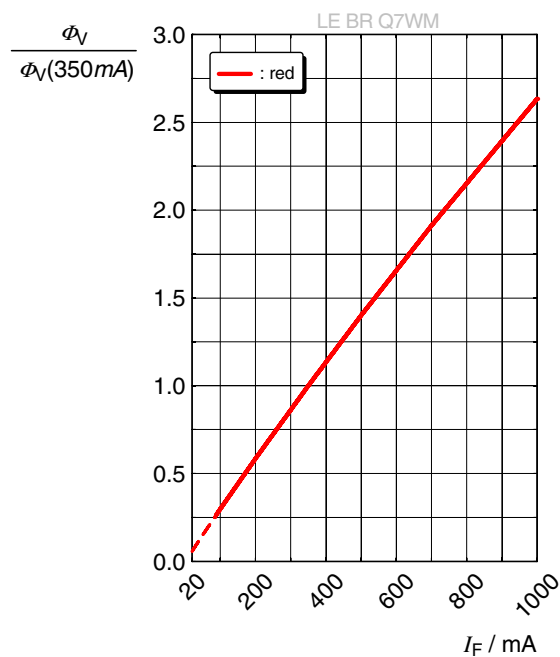
**Relative Radiant Power** 4), 7)

$\Phi_E / \Phi_E(350\text{ mA}) = f(I_F); T_J = 25\text{ }^\circ\text{C}$



**Relative Luminous Flux** 4), 7)

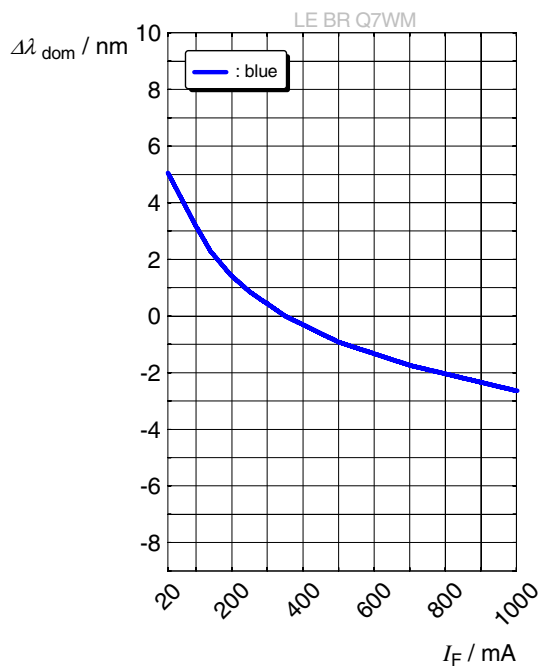
$\Phi_V / \Phi_V(350\text{ mA}) = f(I_F); T_J = 25\text{ }^\circ\text{C}$





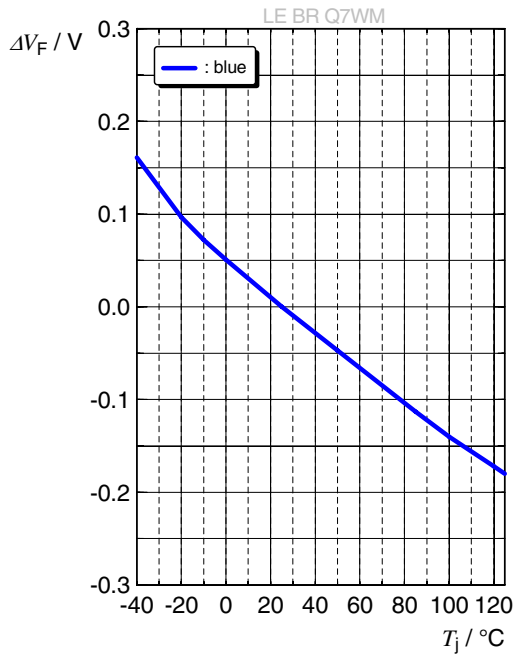
## Dominant Wavelength <sup>4)</sup>

$$\Delta\lambda_{\text{dom}} = f(I_F); T_J = 25\text{ °C}$$



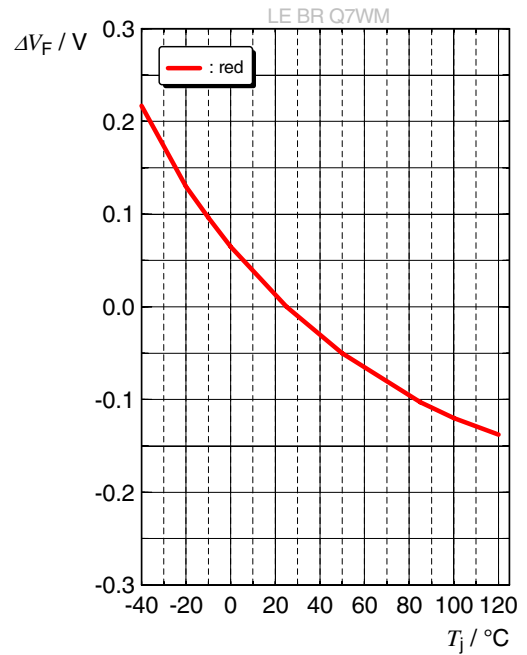
**Forward Voltage** <sup>4)</sup>

$$\Delta V_F = V_F - V_F(25\text{ }^\circ\text{C}) = f(T_j); I_F = 350\text{ mA}$$



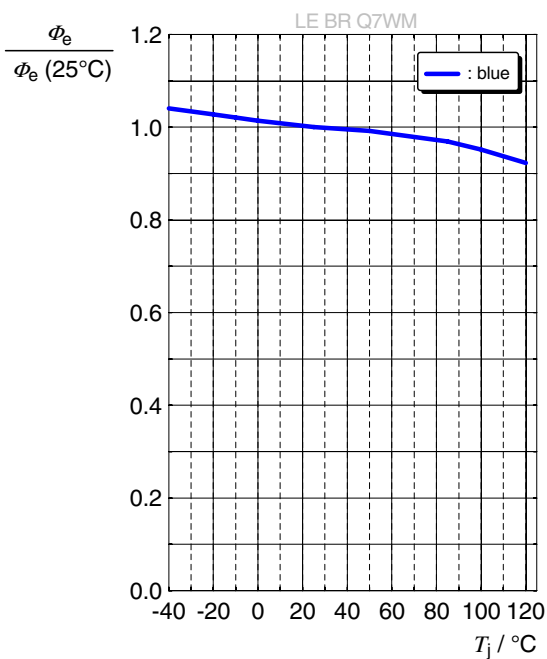
**Forward Voltage** <sup>4)</sup>

$$\Delta V_F = V_F - V_F(25\text{ }^\circ\text{C}) = f(T_j); I_F = 350\text{ mA}$$



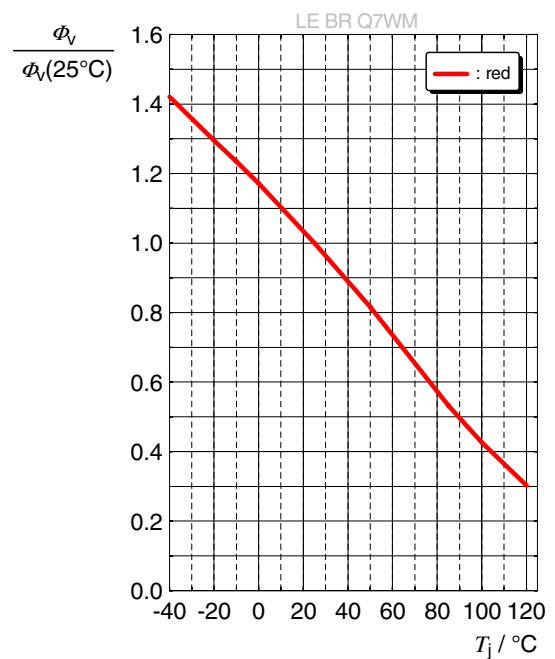
**Relative Radiant Power** <sup>4)</sup>

$$\Phi_E / \Phi_E(25\text{ }^\circ\text{C}) = f(T_j); I_F = 350\text{ mA}$$



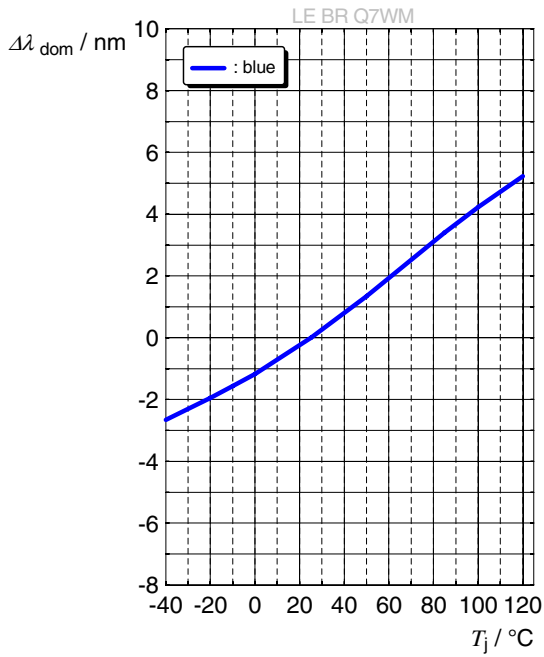
**Relative Luminous Flux** <sup>4)</sup>

$$\Phi_V / \Phi_V(25\text{ }^\circ\text{C}) = f(T_j); I_F = 350\text{ mA}$$



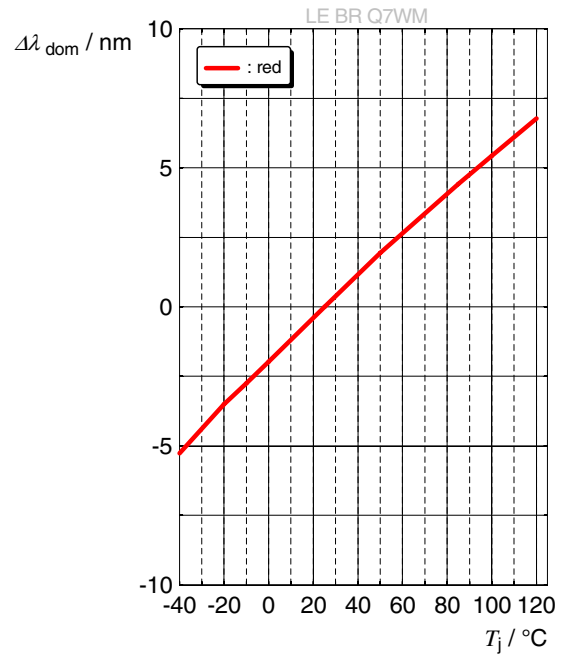
### Dominant Wavelength <sup>4)</sup>

$$\Delta\lambda_{\text{dom}} = \lambda_{\text{dom}} - \lambda_{\text{dom}}(25\text{ °C}) = f(T_j); I_F = 350\text{ mA}$$

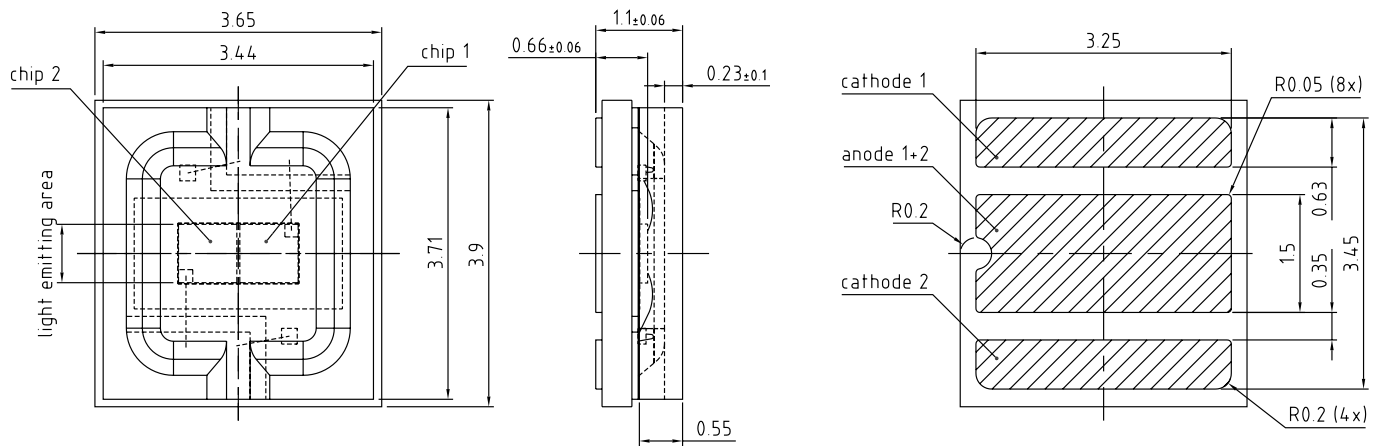


### Dominant Wavelength <sup>4)</sup>

$$\Delta\lambda_{\text{dom}} = \lambda_{\text{dom}} - \lambda_{\text{dom}}(25\text{ °C}) = f(T_j); I_F = 350\text{ mA}$$



## Dimensional Drawing <sup>8)</sup>



general tolerance ±0.1

lead finish Au 

C67062-A0205-A1KA-04

## Further Information:

**Approximate Weight:** 46.0 mg

**Corrosion test:** Class: 3B  
 Test condition: 40°C / 90 % RH / 15 ppm H<sub>2</sub>S / 14 days (stricter than IEC 60068-2-43)

**ESD advice:** The device is protected by ESD device which is connected in parallel to the Chip.

## Electrical Internal Circuit

Pin Assignment:

P1 : cathode chip 1

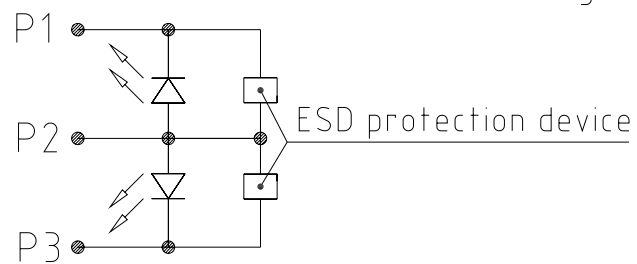
P2 : anode chip 1 + chip 2

P3 : cathode chip 2

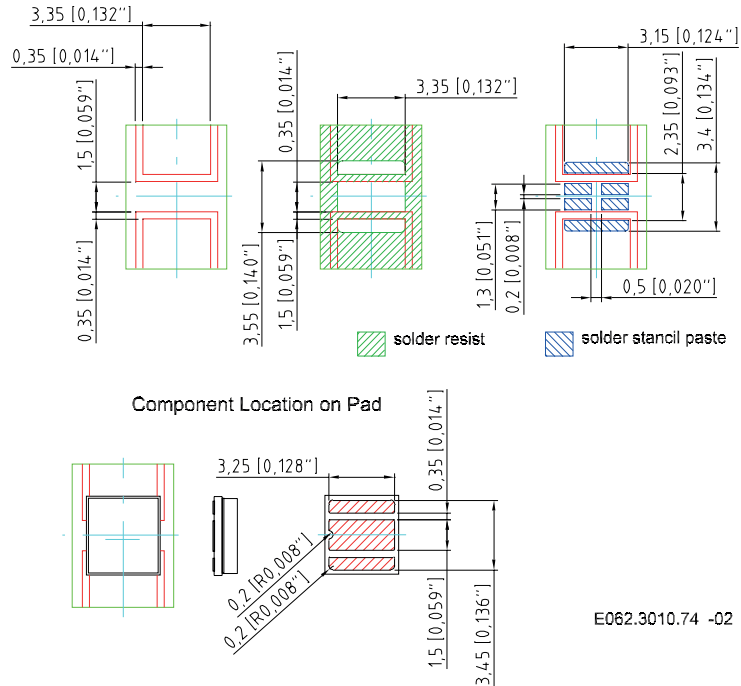
Chip 1 : Blue

Chip 2 : Red

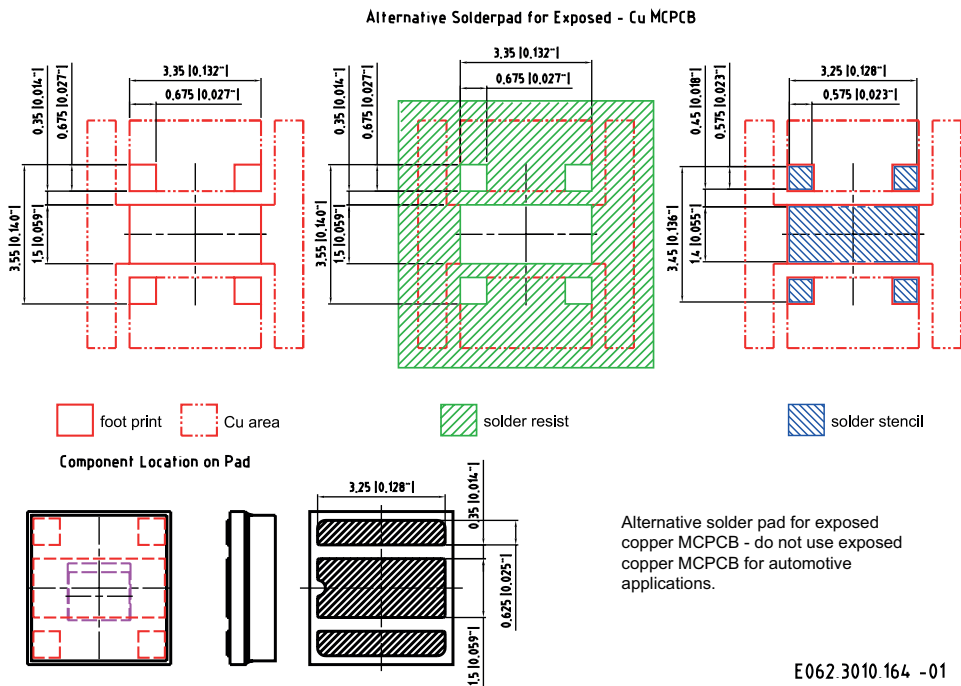
Electrical Internal Circuit and Pin Assignment



### Recommended Solder Pad <sup>8)</sup>



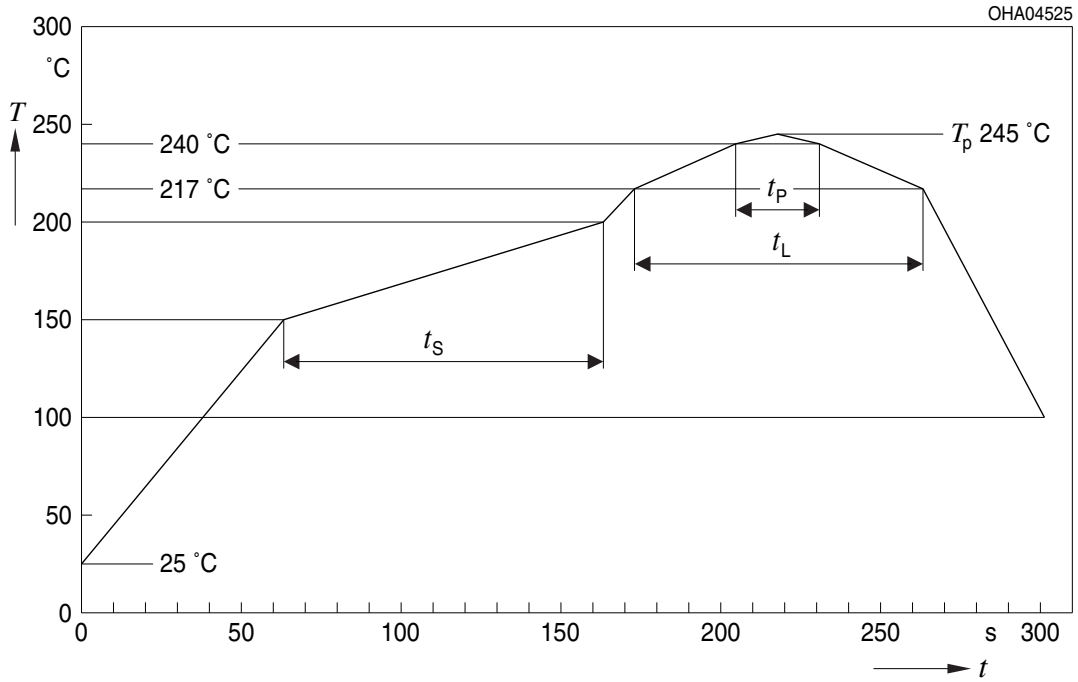
### Recommended Solder Pad <sup>8)</sup>



Exposed Copper MCPCB must not exceed thickness of 1mm. For superior solder joint connectivity results we recommend soldering under standard nitrogen atmosphere. Package not suitable for any kind of wet cleaning or ultrasonic cleaning. In any case the solder pad design shall be validated under customer application conditions.

## Reflow Soldering Profile

Product complies to MSL Level 2 acc. to JEDEC J-STD-020E

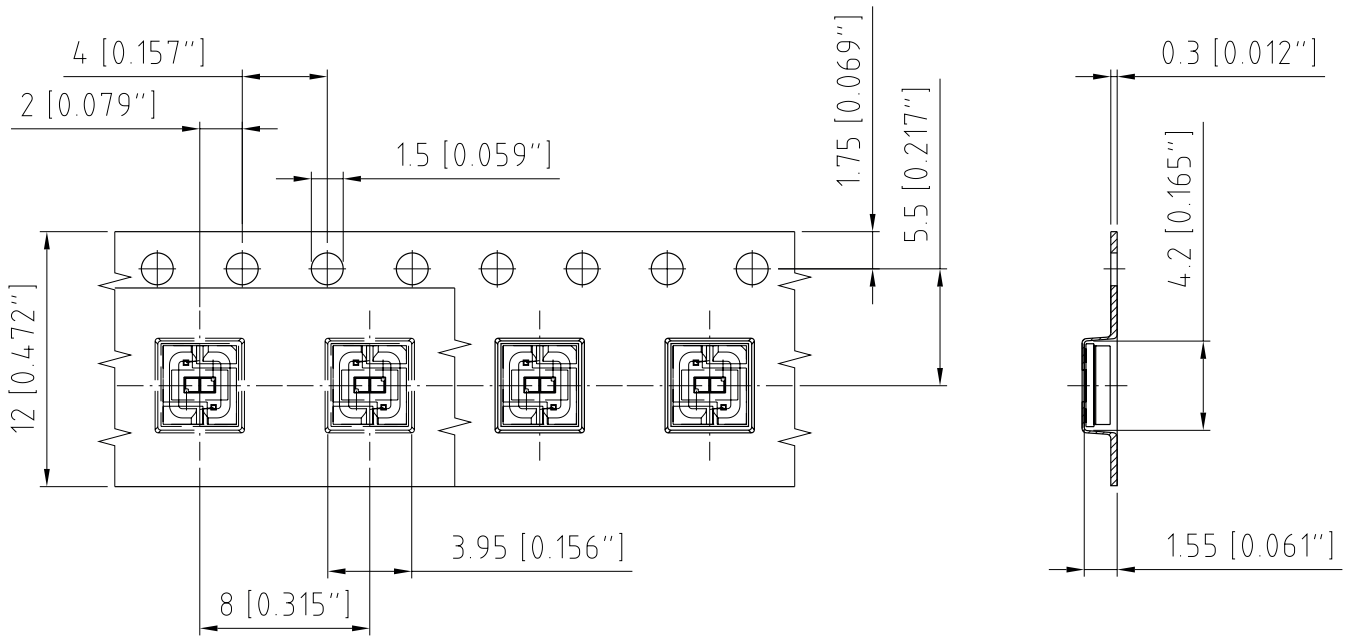


Profile Feature	Symbol	Pb-Free (SnAgCu) Assembly			Unit
		Minimum	Recommendation	Maximum	
Ramp-up rate to preheat <sup>*)</sup> 25 °C to 150 °C			2	3	K/s
Time $t_s$ $T_{Smin}$ to $T_{Smax}$	$t_s$	60	100	120	s
Ramp-up rate to peak <sup>*)</sup> $T_{Smax}$ to $T_p$			2	3	K/s
Liquidus temperature	$T_L$		217		°C
Time above liquidus temperature	$t_L$		80	100	s
Peak temperature	$T_p$		245	260	°C
Time within 5 °C of the specified peak temperature $T_p - 5 \text{ K}$	$t_p$	10	20	30	s
Ramp-down rate* $T_p$ to 100 °C			3	6	K/s
Time 25 °C to $T_p$				480	s

All temperatures refer to the center of the package, measured on the top of the component

\* slope calculation  $DT/Dt$ :  $Dt$  max. 5 s; fulfillment for the whole T-range

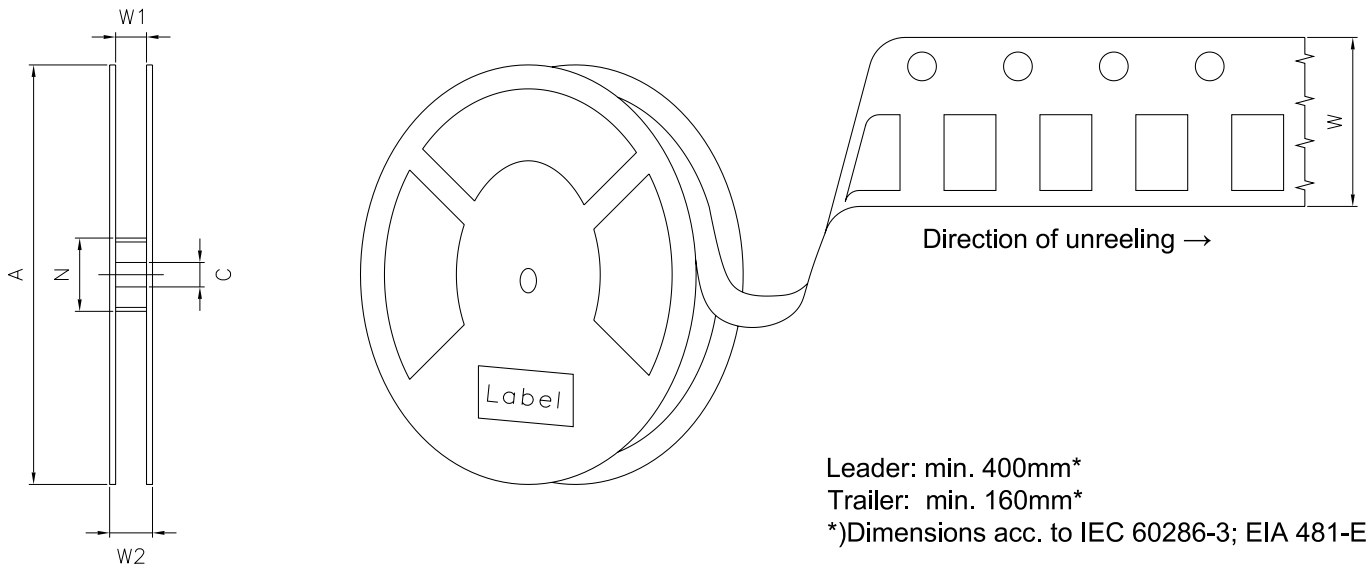
**Taping** <sup>8)</sup>



C63062-A4059-B5-03



**Tape and Reel** <sup>9)</sup>



**Reel Dimensions**

A	W	N <sub>min</sub>	W <sub>1</sub>	W <sub>2max</sub>	Pieces per PU
180 mm	12 + 0.3 / - 0.1 mm	60 mm	12.4 + 2 mm	18.4 mm	500

### Barcode-Product-Label (BPL)

**OSRAM Opto Semiconductors** LX XXXX BIN1: XX-XX-X-XXX-X

RoHS Compliant

(6P) BATCH NO: 1234567890 ML Temp ST  
X XXX °C X

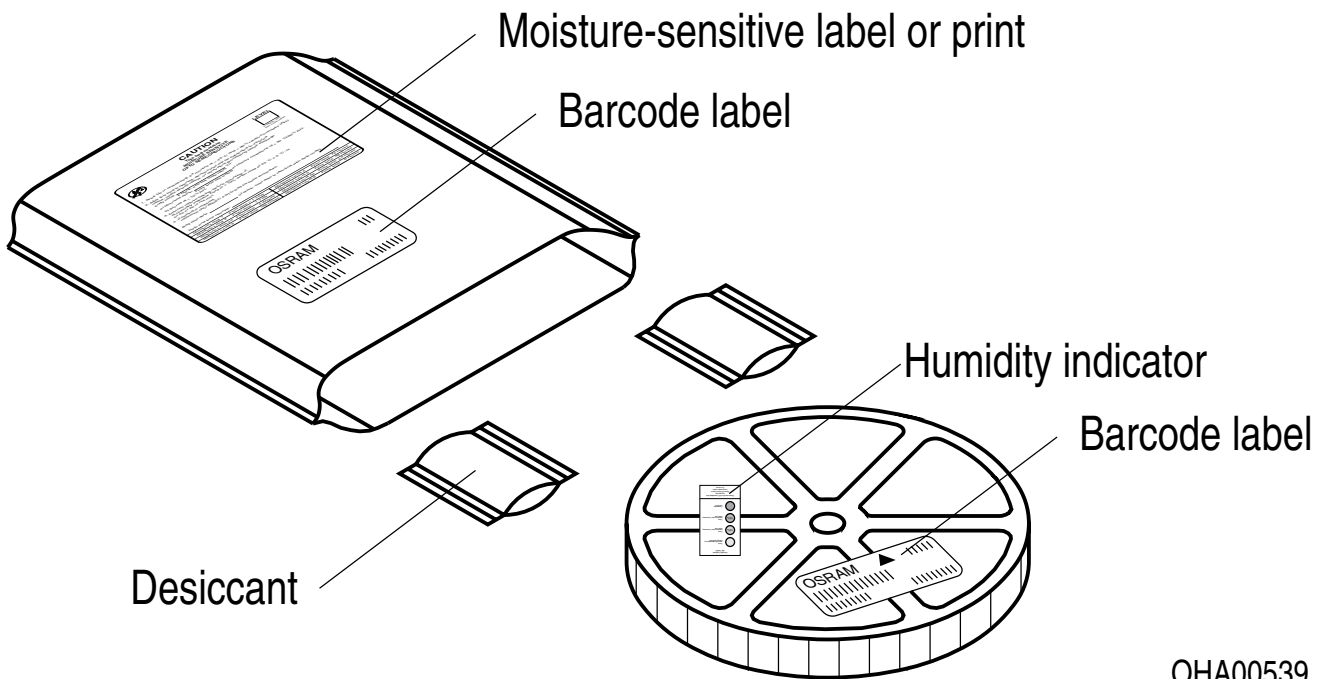
(1T) LOT NO: 1234567890 (9D) D/C: 1234 Pack: RXX  
DEMY XXX  
X\_X123\_1234.1234 X

(X) PROD NO: 123456789(Q)QTY: 9999 (G) GROUP: XX-XX-X-X

The diagram shows a rectangular label with rounded corners. It contains the OSRAM logo and company name at the top left. To the right are fields for 'LX XXXX' and 'BIN1: XX-XX-X-XXX-X'. Below the logo is a 'RoHS Compliant' statement. The label features three horizontal barcode sections. The first is labeled '(6P) BATCH NO: 1234567890' and is accompanied by a 'no liquid' symbol and 'ML Temp ST X XXX °C X'. The second is labeled '(1T) LOT NO: 1234567890' and '(9D) D/C: 1234' and is accompanied by 'Pack: RXX', 'DEMY XXX', and 'X\_X123\_1234.1234 X'. The third is labeled '(X) PROD NO: 123456789(Q)QTY: 9999 (G) GROUP: XX-XX-X-X'. A square QR code is located on the right side of the label.

OHA04563

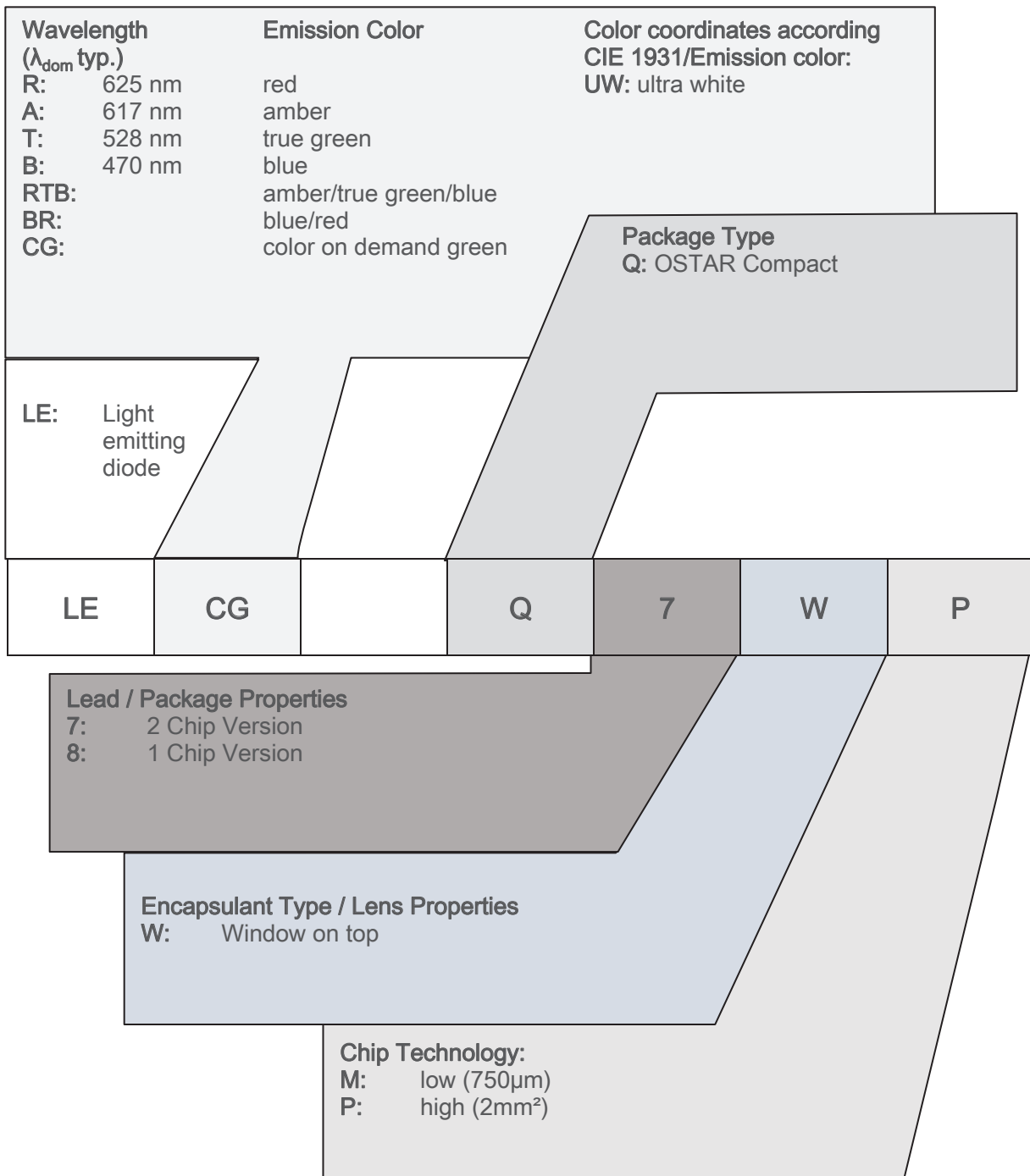
### Dry Packing Process and Materials <sup>8)</sup>



OHA00539

Moisture-sensitive product is packed in a dry bag containing desiccant and a humidity card according JEDEC-STD-033.

## Type Designation System



## Notes

The evaluation of eye safety occurs according to the standard IEC 62471:2006 (photo biological safety of lamps and lamp systems). Within the risk grouping system of this IEC standard, the device specified in this data sheet fall into the class **moderate risk (exposure time 0.25 s)**. Under real circumstances (for exposure time, conditions of the eye pupils, observation distance), it is assumed that no endangerment to the eye exists from these devices. As a matter of principle, however, it should be mentioned that intense light sources have a high secondary exposure potential due to their blinding effect. When looking at bright light sources (e.g. headlights), temporary reduction in visual acuity and afterimages can occur, leading to irritation, annoyance, visual impairment, and even accidents, depending on the situation.

Subcomponents of this device contain, in addition to other substances, metal filled materials including silver. Metal filled materials can be affected by environments that contain traces of aggressive substances. Therefore, we recommend that customers minimize device exposure to aggressive substances during storage, production, and use. Devices that showed visible discoloration when tested using the described tests above did show no performance deviations within failure limits during the stated test duration. Respective failure limits are described in the IEC60810.

For further application related information please visit [www.osram-os.com/appnotes](http://www.osram-os.com/appnotes)

## Disclaimer

### **Attention please!**

The information describes the type of component and shall not be considered as assured characteristics. Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version on the OSRAM OS website.

### **Packing**

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

### **Product and functional safety devices/applications or medical devices/applications**

OSRAM OS components are not developed, constructed or tested for the application as safety relevant component or for the application in medical devices.

OSRAM OS products are not qualified at module and system level for such application.

In case buyer – or customer supplied by buyer – considers using OSRAM OS components in product safety devices/applications or medical devices/applications, buyer and/or customer has to inform the local sales partner of OSRAM OS immediately and OSRAM OS and buyer and /or customer will analyze and coordinate the customer-specific request between OSRAM OS and buyer and/or customer.

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## Glossary

- 1) **Brightness:** Brightness values are measured during a current pulse of typically 25 ms, with an internal reproducibility of  $\pm 8\%$  and an expanded uncertainty of  $\pm 11\%$  (acc. to GUM with a coverage factor of  $k = 3$ ).
- 2) **Reverse Operation:** This product is intended to be operated applying a forward current within the specified range. Applying any continuous reverse bias or forward bias below the voltage range of light emission shall be avoided because it may cause migration which can change the electro-optical characteristics or damage the LED.
- 3) **Wavelength:** The wavelength is measured at a current pulse of typically 25 ms, with an internal reproducibility of  $\pm 0.5$  nm and an expanded uncertainty of  $\pm 1$  nm (acc. to GUM with a coverage factor of  $k = 3$ ).
- 4) **Typical Values:** Due to the special conditions of the manufacturing processes of semiconductor devices, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.
- 5) **Forward Voltage:** Forward voltages are tested at a current pulse duration of 1 ms and a tolerance of  $\pm 0.05$  V and an expanded uncertainty of  $\pm 0.1$  V (acc. to GUM with a coverage factor of  $k = 3$ ).
- 6) **Thermal Resistance:**  $R_{th\ max}$  is based on statistic values ( $6\sigma$ ).
- 7) **Characteristic curve:** In the range where the line of the graph is broken, you must expect higher differences between single devices within one packing unit.
- 8) **Tolerance of Measure:** Unless otherwise noted in drawing, tolerances are specified with  $\pm 0.1$  and dimensions are specified in mm.
- 9) **Tape and Reel:** All dimensions and tolerances are specified acc. IEC 60286-3 and specified in mm.

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## Revision History

Version	Date	Change
1.7	2018-12-19	Wavelength Groups Characteristics
1.8	2020-04-16	Dimensional Drawing Schematic Transportation Box Dimensions of Transportation Box
1.9	2020-07-09	Wavelength Groups
1.10	2020-10-06	Maximum Ratings
1.11	2020-12-16	Characteristics
1.12	2021-01-25	Wavelength Groups
1.13	2021-09-23	Recommended Solder Pad

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按照中国的相关法规和标准，不含有毒有害物质或元素。